

FS10KM-9A

HIGH-SPEED SWITCHING USE

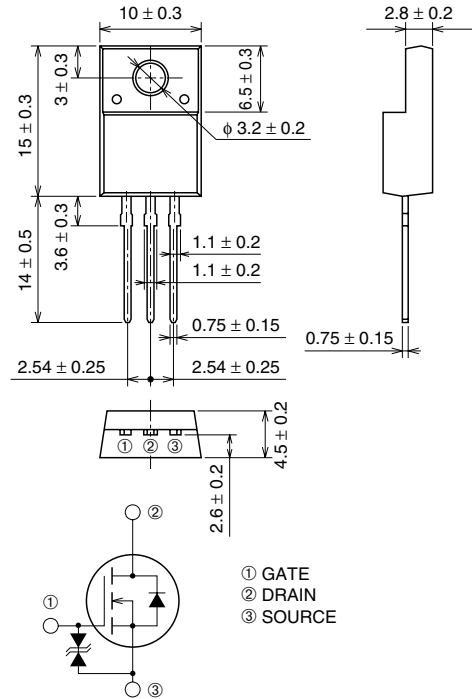
FS10KM-9A



- 10V DRIVE
- V_{DS} 450V
- $r_{DS(ON)}$ (MAX) 0.73Ω
- I_D 10A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

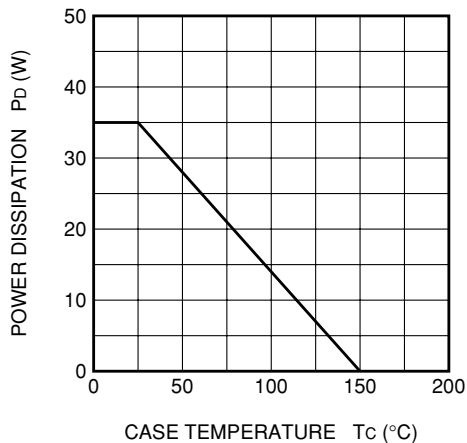
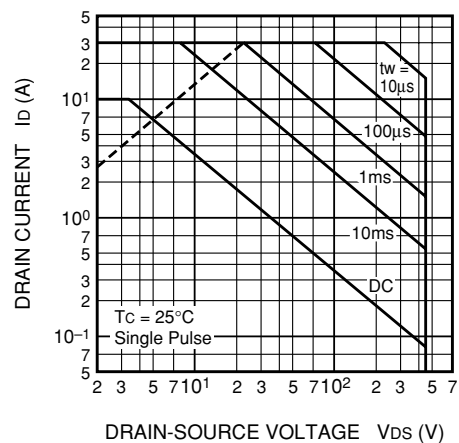
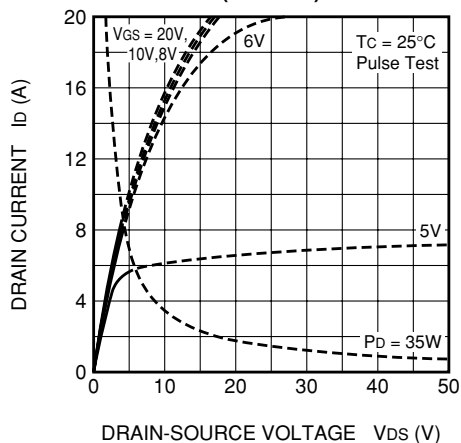
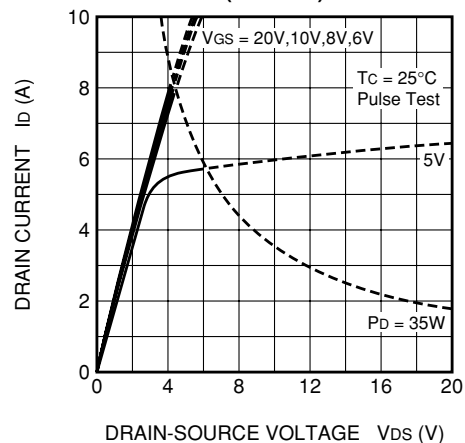
SMPS, AC-adaptor, Power supply of Printer, Copier, TV, VCR. etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	450	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		10	A
I_{DM}	Drain current (Pulsed)		30	A
I_{DA}	Avalanche current (Pulsed)	$L = 200\mu H$	10	A
P_D	Maximum power dissipation		35	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

ELECTRICAL CHARACTERISTICS ($T_{ch} = 25^{\circ}\text{C}$)

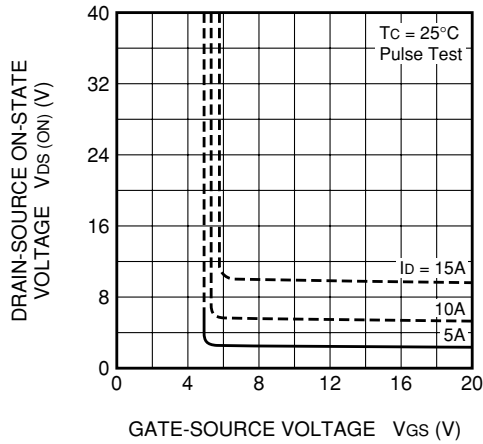
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	450	—	—	V
$V_{(BR)GSS}$	Gate-source breakdown voltage	$I_{GS} = \pm 100\mu\text{A}$, $V_{DS} = 0\text{V}$	± 30	—	—	V
I_{GSS}	Gate-source leakage current	$V_{GS} = \pm 25\text{V}$, $V_{DS} = 0\text{V}$	—	—	± 10	μA
I_{DSS}	Drain-source leakage current	$V_{DS} = 450\text{V}$, $V_{GS} = 0\text{V}$	—	—	1	mA
$V_{GS(th)}$	Gate-source threshold voltage	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
$r_{DS(on)}$	Drain-source on-state resistance	$I_D = 5\text{A}$, $V_{GS} = 10\text{V}$	—	0.58	0.73	Ω
$V_{DS(on)}$	Drain-source on-state voltage	$I_D = 5\text{A}$, $V_{GS} = 10\text{V}$	—	2.90	3.65	V
$ y_{fs} $	Forward transfer admittance	$I_D = 5\text{A}$, $V_{DS} = 10\text{V}$	5.4	9.0	—	S
C_{iss}	Input capacitance	$V_{DS} = 25\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	—	1100	—	pF
C_{oss}	Output capacitance		—	120	—	pF
C_{rss}	Reverse transfer capacitance		—	25	—	pF
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 200\text{V}$, $I_D = 5\text{A}$, $V_{GS} = 10\text{V}$, $R_{GEN} = R_{GS} = 50\Omega$	—	20	—	ns
t_r	Rise time		—	30	—	ns
$t_{d(off)}$	Turn-off delay time		—	140	—	ns
t_f	Fall time		—	40	—	ns
V_{SD}	Source-drain voltage	$I_S = 5\text{A}$, $V_{GS} = 0\text{V}$	—	1.5	2.0	V
$R_{th(ch-c)}$	Thermal resistance	Channel to case	—	—	3.57	$^{\circ}\text{C/W}$

PERFORMANCE CURVES**POWER DISSIPATION DERATING CURVE****MAXIMUM SAFE OPERATING AREA****OUTPUT CHARACTERISTICS (TYPICAL)****OUTPUT CHARACTERISTICS (TYPICAL)**

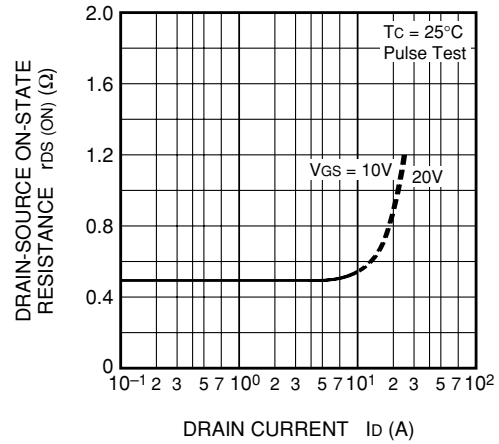
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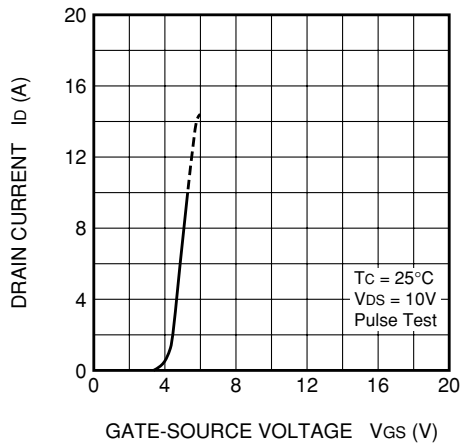
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



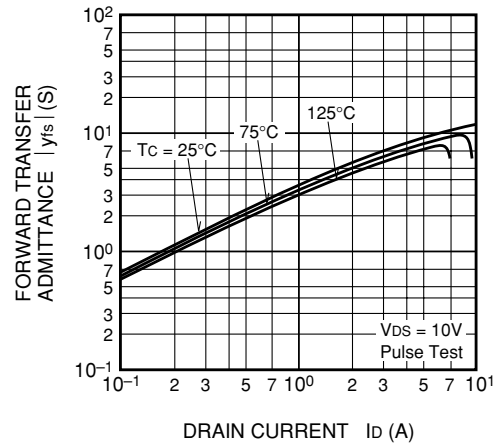
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



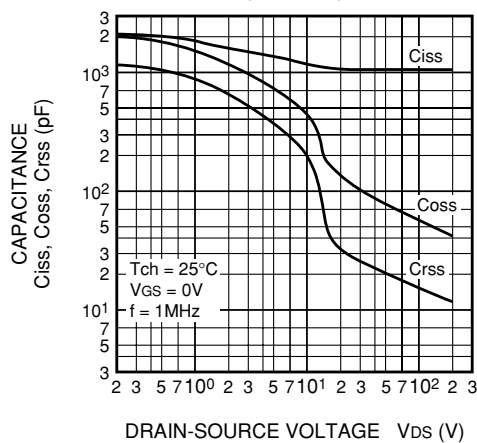
TRANSFER CHARACTERISTICS
(TYPICAL)



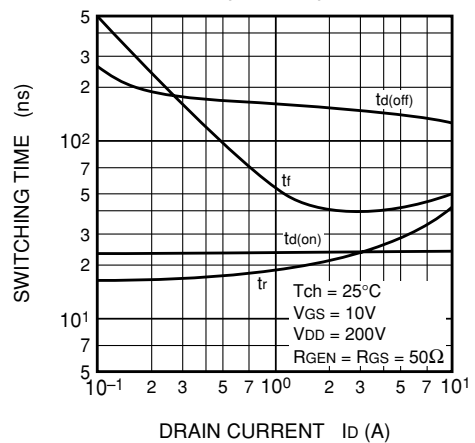
FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)



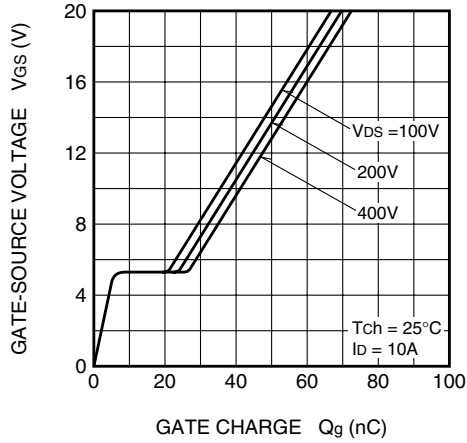
CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



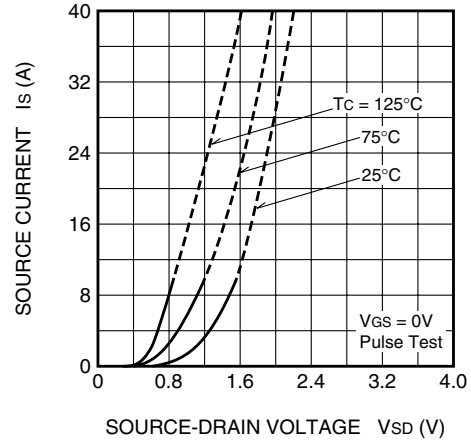
SWITCHING CHARACTERISTICS
(TYPICAL)



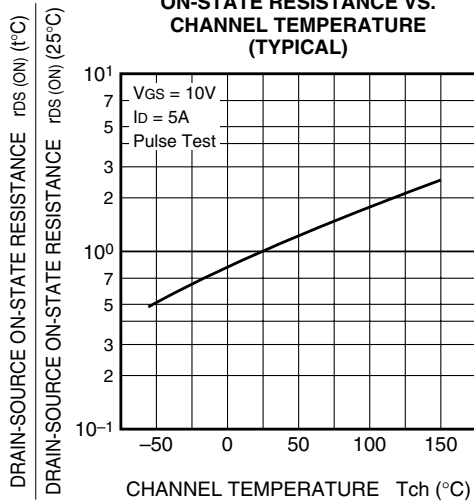
GATE-SOURCE VOLTAGE
VS. GATE CHARGE
(TYPICAL)



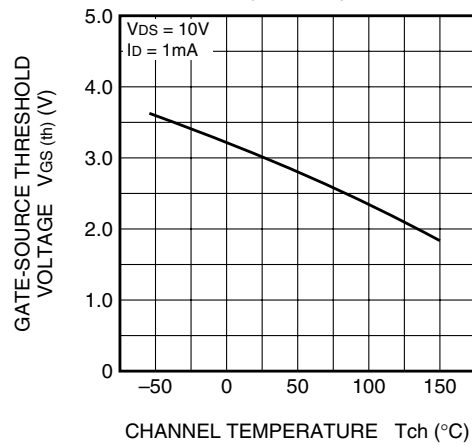
SOURCE-DRAIN DIODE
FORWARD CHARACTERISTICS
(TYPICAL)



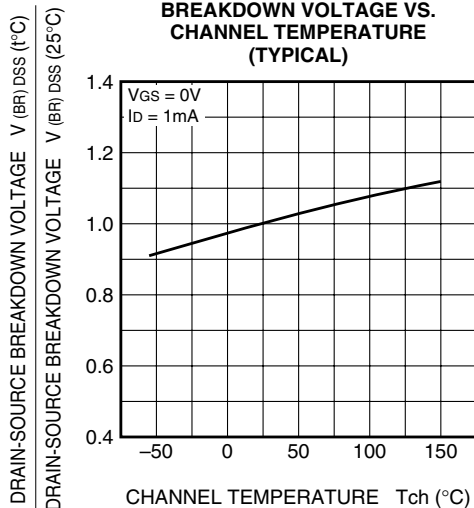
ON-STATE RESISTANCE VS.
CHANNEL TEMPERATURE
(TYPICAL)



THRESHOLD VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)



BREAKDOWN VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)



TRANSIENT THERMAL IMPEDANCE
CHARACTERISTICS

